## VS-MBRS130LTRPbF

**Vishay Semiconductors** 

RoHS

COMPLIANT

High Performance Schottky Rectifier, 1.0 A

### **FEATURES**

- · Small foot print, surface mountable
- · Very low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-MBRS130LTRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |                           |    |  |  |  |  |
|-----------------------------------|---|---------------------------|----|--|--|--|--|
| SYMBOL                            | CHARACTERISTICS                               | CHARACTERISTICS VALUES UN |    |  |  |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                          | 1.0                       | А  |  |  |  |  |
| V <sub>RRM</sub>                  |   | 30                        | V  |  |  |  |  |
| I <sub>FSM</sub>                  | $t_p = 5 \ \mu s \ sine$                      | 230                       | А  |  |  |  |  |
| V <sub>F</sub>                    | 1.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.30                      | V  |  |  |  |  |
| TJ                                | Range   | -55 to +125               | °C |  |  |  |  |

| VOLTAGE RATINGS                      |                  |                  |       |  |  |  |
|--------------------------------------|------------------|------------------|-------|--|--|--|
| PARAMETER                            | SYMBOL           | VS-MBRS130LTRPbF | UNITS |  |  |  |
| Maximum DC reverse voltage           | V <sub>R</sub>   | 30               | V     |  |  |  |
| Maximum working peak reverse voltage | V <sub>RWM</sub> | 30               | v     |  |  |  |

| ABSOLUTE MAXIMUM RATINGS        |                    |   |   |        |       |  |
|---------------------------------|--------------------|---|---|--------|-------|--|
| PARAMETER                       | SYMBOL             | TEST CONDITIONS   |   | VALUES | UNITS |  |
| Maximum average forward current | I <sub>F(AV)</sub> | 50 % duty cycle at $T_L$ = 112 °C, rectangular waveform   |   | 1.0    |       |  |
| Maximum peak one cycle          | I <sub>FSM</sub>   | 5 µs sine or 3 µs rect. pulse   | Following any rated load condition and with rated | 230    | А     |  |
| non-repetitive surge current    |                    | 10 ms sine or 6 ms rect. pulse  | $V_{\text{RRM}}$ applied                          | 40     |       |  |
| Non-repetitive avalanche energy | E <sub>AS</sub>    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 6 mH   |   | 3.0    | mJ    |  |
| Repetitive avalanche current    | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s<br>Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical |   | 1.0    | А     |  |



**PRODUCT SUMMARY** 

Package

I<sub>F(AV)</sub>

 $V_R$ 

V<sub>F</sub> at I<sub>F</sub>

I<sub>RM</sub> max.

T<sub>J</sub> max.

Diode variation

 $E_{AS}$ 

www.vishay.com



SMB

1.0 A

30 V

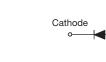
0.30 V

20 mA at 125 °C

125 °C

Single die

3.0 mJ





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| ELECTRICAL SPECIFICATIONS       |                                |  |                           |        |      |  |
|---------------------------------|--------------------------------|--|---------------------------|--------|------|--|
| PARAMETER                       | SYMBOL                         | TEST CO  | VALUES                    | UNITS  |      |  |
|                                 | V <sub>FM</sub> <sup>(1)</sup> | 1 A  | T <sub>J</sub> = 25 °C    | 0.420  | V    |  |
| Maximum forward valtage drep    |                                | 2 A  |                           | 0.470  |      |  |
| Maximum forward voltage drop    |                                | 1 A  | - T <sub>J</sub> = 125 °C | 0.300  |      |  |
|                                 |                                | 2 A  |                           | 0.370  |      |  |
|                                 | I <sub>RM</sub> <sup>(1)</sup> | T <sub>J</sub> = 25 °C   |                           | 1      |      |  |
| Maximum reverse leakage current |                                | T <sub>J</sub> = 100 °C  | $V_R = Rated V_R$         | 10     | mA   |  |
|                                 |                                | T <sub>J</sub> = 125 °C  |                           | 20     |      |  |
| Maximum junction capacitance    | CT                             | $V_{R}$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 $^{\circ}\mathrm{C}$ |                           | 200    | pF   |  |
| Typical series inductance       | L <sub>S</sub>                 | Measured lead to lead 5 mm from package body                                       |                           | 2.0    | nH   |  |
| Maximum voltage rate of change  | dV/dt                          | Rated V <sub>R</sub>   |                           | 10 000 | V/µs |  |

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

| THERMAL - MECHANICAL SPECIFICATIONS             |                                  |                                      |             |       |  |
|---|----------------------------------|--------------------------------------|-------------|-------|--|
| PARAMETER                                       | SYMBOL                           | TEST CONDITIONS                      | VALUES      | UNITS |  |
| Maximum junction temperature range              | T <sub>J</sub> <sup>(1)</sup>    |                                      | -55 to +125 | °C    |  |
| Maximum storage temperature range               | T <sub>Stg</sub>                 |                                      | -55 to +150 | C     |  |
| Maximum thermal resistance, junction to lead    | R <sub>thJL</sub> <sup>(2)</sup> | DC operation<br>See fig. 4           | 25          | °C/W  |  |
| Maximum thermal resistance, junction to ambient | R <sub>thJA</sub>                | DC operation                         | 80          | 0/10  |  |
| Approvimeto weight                              |                                  |                                      | 0.10        | g     |  |
| Approximate weight                              |                                  |                                      | 0.003       | oz.   |  |
| Marking device                                  |                                  | Case style SMB (similar to DO-214AA) | 13          | L     |  |

#### Notes

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB



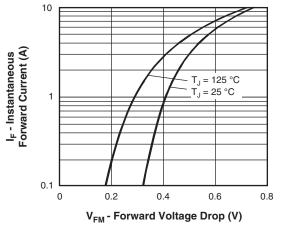


Fig. 1 - Maximum Forward Voltage Drop Characteristics

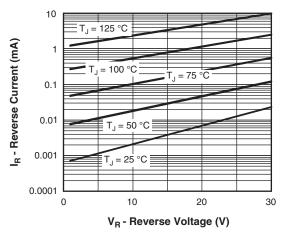
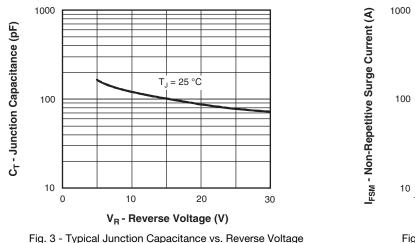
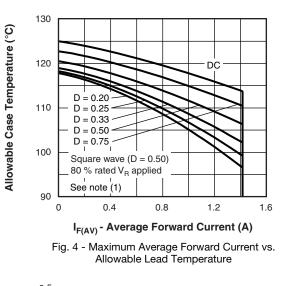


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage



### **Vishay Semiconductors**



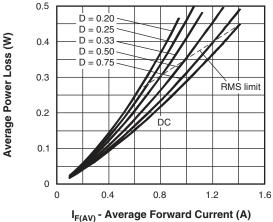


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

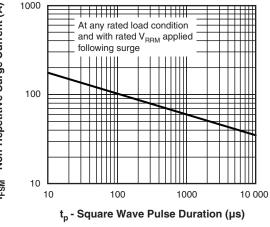


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

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## Vishay Semiconductors



### **ORDERING INFORMATION TABLE**

| Device code | VS-              | MBR            | S              | 1                                 | 30  | L     | TR | PbF |
|-------------|------------------|----------------|----------------|-----------------------------------|-----|-------|----|-----|
|             |                  | 2              | 3              | 4                                 | 5   | 6     | 7  | 8   |
|             | 1<br>2<br>3<br>4 | - Sch<br>- S = | ottky M<br>SMB | niconduc<br>BR serie<br>ng (1 = 1 | es  | oduct |    |     |
|             | 5                |                |                | ng (30 =                          | -   |       |    |     |
|             | 6                | - L=           | low forv       | vard volt                         | age |       |    |     |
|             | 7.               | - TR           | = tape a       | and reel                          |     |       |    |     |
|             | 8                | - PbF          | = lead         | (Pb)-fre                          | е   |       |    |     |

| ORDERING INFORMATION (Example) |   |      |                                    |  |  |
|--------------------------------|---|------|------------------------------------|--|--|
| PREFERRED P/N                  | PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION |      |                                    |  |  |
| VS-MBRS130LTRPbF               | 5BT   | 3200 | 13" diameter plastic tape and reel |  |  |

| LINKS TO RELATED DOCUMENTS                 |                          |  |  |  |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95401</u> |                          |  |  |  |
| Part marking information                   | www.vishay.com/doc?95403 |  |  |  |
| Packaging information                      | www.vishay.com/doc?95404 |  |  |  |

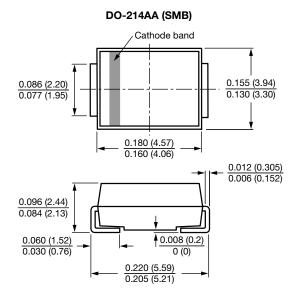


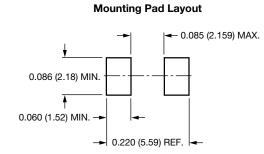
## **Outline Dimensions**

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**SMB** 

### **DIMENSIONS** in inches (millimeters)







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